

<b>PCN Number:</b>	20230829004.2		<b>PCN Date:</b>	August 30, 2023	
<b>Title:</b>	Qualification of LFAB as an additional Fab site and CD-PR as an additional Probe Site for select devices				
<b>Customer Contact:</b>	Change Management team		<b>Dept:</b>	Quality Services	
<b>Proposed 1<sup>st</sup> Ship Date:</b>	Feb 29, 2024		<b>Sample requests accepted until:</b>	Sep 29, 2023*	
<b>*Sample requests received after September 29, 2023 will not be supported.</b>					
<b>Change Type:</b>					
<input type="checkbox"/>	Assembly Site	<input type="checkbox"/>	Design	<input type="checkbox"/>	Wafer Bump Material
<input type="checkbox"/>	Assembly Process	<input type="checkbox"/>	Data Sheet	<input type="checkbox"/>	Wafer Bump Process
<input type="checkbox"/>	Assembly Materials	<input type="checkbox"/>	Part number change	<input checked="" type="checkbox"/>	Wafer Fab Site
<input type="checkbox"/>	Mechanical Specification	<input checked="" type="checkbox"/>	Test Site	<input type="checkbox"/>	Wafer Fab Material
<input type="checkbox"/>	Packing/Shipping/Labeling	<input type="checkbox"/>	Test Process	<input type="checkbox"/>	Wafer Fab Process

**Description of Change:**

Texas Instruments is pleased to announce the qualification of its LFAB fabrication facility as an additional Wafer Fab source and CD-PR as additional probe site options for the selected devices listed in the "Product Affected" section.

Current Fab/Probe Site				Additional Fab/Probe Sites			
Current Fab Site	Fab Process	Probe Site	Wafer Diameter	Additional Fab Site	Fab Process	Probe Site	Wafer Diameter
UMC12i	F65	CLARK-PR	300mm	LFAB	F65	CD-PR	300mm

Test coverage, insertions, conditions will remain consistent with current testing.

**Reason for Change:**


Continuity of supply

**Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):**

None

**Changes to product identification resulting from this PCN:**

**Device Symbol:**



F280025CPMS  
\$\$#-YMLLLLS  
G4

Package Pin 1

YMLLLLS = Lot Trace Code

YM = 2-Digit Year/Month Code

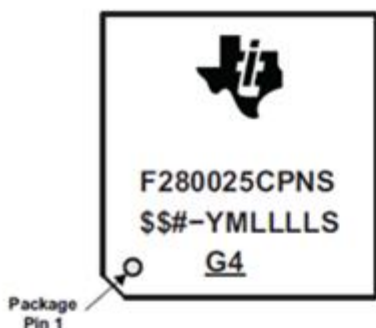
LLLL = Assembly Lot

S = Assembly Site Code

\$\$ = Wafer Fab Code (one or two characters) as applicable

# = Silicon Revision Code

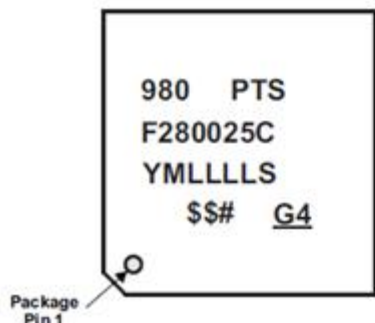
G4 = Green (Low Halogen and RoHS-compliant)



YMLLLLS = Lot Trace Code

YM = 2-Digit Year/Month Code  
 LLLL = Assembly Lot  
 S = Assembly Site Code  
 \$\$ = Wafer Fab Code (one or two characters) as applicable  
 # = Silicon Revision Code

G4 = Green (Low Halogen and RoHS-compliant)



YMLLLLS = Lot Trace Code

YM = 2-Digit Year/Month Code  
 LLLL = Assembly Lot  
 S = Assembly Site Code  
 980 = TI E.I.A. Code  
 \$\$ = Wafer Fab Code (one or two characters) as applicable  
 # = Silicon Revision Code

G4 = Green (Low Halogen and RoHS-compliant)

#### Original Fab Field:

\$\$ = \$7 → UMC 12i

#### Updated Fab Field:

\$\$ = \$7 → UMC 12i

Or

\$\$ = 3L → LFAB

#### Current Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
UMC 12i	UMI	SGP	Singapore

#### Additional Fab Site Information:

New Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
<b>LFAB</b>	<b>LHI</b>	<b>USA</b>	<b>Lehi</b>

Sample product shipping label (not actual product label)



**TEXAS INSTRUMENTS**  
 MADE IN: Malaysia  
 2DC: 20:  
 MSL 2 /260C/1 YEAR SEAL DT  
 MSL 1 /235C/UNLIM 03/29/04  
 OPT:  
 ITEM: 39  
**LBL: 5A (L)T0:1750**



(1P) **SN74LS07NSR**  
 (Q) **2000** (D) **0336**  
 (31T) LOT: 3959047MLA  
 (4W) TKY(1T) 7523483SI2  
 (P)  
 (2P) REV: (V) 0033317  
 (20L) CSO: SHE (21L) CCO:USA  
 (22L) ASO: MLA (23L) ACO: MYS

#### Product Affected:

F280021PTQR	F280023PTQR	F280025CPTQR	F280025PTQR
F280023PMQR	F280025CPMQR	F280025PMQR	SB280025PNQR
F280023PNQR	F280025CPNQR	F280025PNQR	

## Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: F280025CPNQR	QBS Reference: TMS320F28379SPTPQ
Test Group A - Accelerated Environment Stress Tests									
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Preconditioning	MSL3 260C	-	-QBS	3/363/0
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST	110C/85%RH	264 Hours	-QBS	3/231/0
AC/UHAST	A3	JEDEC JESD22-A102/JEDEC JESD22-A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	-QBS	3/231/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	-QBS	3/231/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	-QBS	1/5/0
HTSL	A6	JEDEC JESD22-A103	1	45	High Temperature Storage Life	150C	1000 Hours	-QBS	3/135/0
Test Group B - Accelerated Lifetime Simulation Tests									
HTOL	B1	JEDEC JESD22-A108	3	77	Life Test	125C	1000 Hours	1/77/0	3/231/0
ELFR	B2	AEC Q100-008	3	77	Early Life Failure Rate	125C	48 Hours	-QBS	3/2400/0
EDR B3	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	150C	1000 hours	-QBS	3/231/0
Test Group C - Package Assembly Integrity Tests									
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	-QBS	3/90/0

Type	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: <a href="#">F280025CPNQR</a>	QBS Reference: <a href="#">TMS320F28379SPTPQ</a>
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	-QBS	3/90/0
<b>Test Group D - Die Fabrication Reliability Tests</b>									
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDb	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
<b>Test Group E - Electrical Verification Tests</b>									
ESD	E2	AEC Q100-002	1	3	ESD HBM	-	2000 Volts	1/3/0	1/3/0
ESD	E3	AEC Q100-011	1	3	ESD CDM	-	750 Volts	1/3/0	1/3/0
LU	E4	AEC Q100-004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	1/6/0
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0	3/90/0
<b>Additional Tests</b>									

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

- Flash memory was programmed and Erased to 20,000 times for B1 and B2 tests

**Ambient Operating Temperature by Automotive Grade Level:**

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

**E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):**

- Room/Hot/Cold : HTOL, ED
- Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

TI Qualification ID: R-CHG-2206-089

[1]-1 unit passed 25C (Q100 requirement) marginal failure at 125C. Appears to be tester repeatability and unrelated to stress test. Refer to QEM-EVAL-2211-00276

**ZVEI ID:** SEM-PW-13, SEM-TF-01

For questions regarding this notice, e-mails can be sent to the Change Management team or your local Field Sales Representative.

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